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. reescale Semiconductor Technical Data

Gallium Arsenide CATV Amplifier Module

# **Features**

- Specified for 79- and 112-Channel Loading
- Excellent Distortion Performance
- Higher Output Capability
- Built-in Input Diode Protection
- GaAs FET Transistor Technology
- Unconditionally Stable Under All Load Conditions
- Output Port Ring Wave Protection

# **Applications**

- CATV Systems Operating in the 47 to 870 MHz Frequency Range
- Output Stage Amplifier in Optical Nodes, Line Extenders and Trunk Distribution Amplifiers for CATV Systems
- Driver Amplifier in Linear General Purpose Applications

# Description

- 24 Vdc Supply, 47 to 870 MHz, CATV GaAs Forward Power Doubler Amplifier Module
- Replaced MHW8247A. There are no form, fit or function changes with this
  part replacement.
- RoHS Compliant

# Document Number: MHW8247AN Rev. 3, 5/2006

5,5,210

**√RoHS** 

# **MHW8247AN**

870 MHz 24.9 dB GAIN 112-CHANNEL GaAs CATV AMPLIFIER MODULE



**CASE 1302-01, STYLE 1** 

# **Table 1. Maximum Ratings**

Rating	Symbol	Value	Unit
RF Voltage Input (Single Tone)	V <sub>in</sub>	+70	dBmV
DC Supply Voltage	V <sub>CC</sub>	+28	Vdc
Operating Case Temperature Range	T <sub>C</sub>	-20 to +100	°C
Storage Temperature Range	T <sub>stg</sub>	-40 to +100	°C

# **Table 2. ESD Maximum Ratings**

Rating	Input Value	Output Value	Unit
Surge Voltage per IEC 1000-4-5	300	300	V
Human Body Model per Mil. Std. 1686	2	2	kV

**Table 3. Electrical Characteristics** ( $V_{CC}$  = 24 Vdc,  $T_{C}$  = +45°C, 75  $\Omega$  system unless otherwise noted)

Characteristic			Min	Тур	Max	Unit
Frequency Range		BW	47	_	870	MHz
Power Gain	870 MHz	Gp	24.4	24.9	25.4	dB
Slope	47-870 MHz	S	0	0.6	1.2	dB
Gain Flatness (40-870 MHz, Peak-to-Valley)			_	_	0.7	dB
Return Loss — Input		IRL				dB
(Z <sub>o</sub> = 75 Ohms)	47-500 MHz		20		_	
	501 - 750 MHz		18			
	751-870 MHz		16	_	_	
Return Loss — Output	ORL				dB	
(Z <sub>o</sub> = 75 Ohms)	47-160 MHz		20		_	
	161-700 MHz		18			
	701-870 MHz		16			



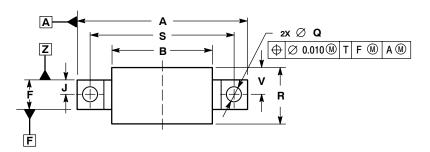
**Table 3. Electrical Characteristics** ( $V_{CC}$  = 24 Vdc,  $T_{C}$  = +45°C, 75  $\Omega$  system unless otherwise noted) (continued)

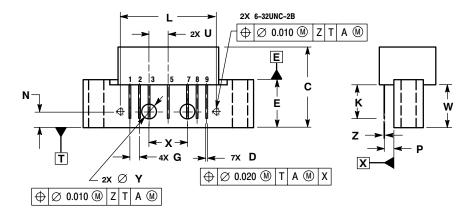
Characteristic Sy			Min	Тур	Max	Unit
Composite Second Order (Vout = +48 dBmV/ch., Worst Case) (Vout = +48 dBmV/ch., Worst Case) (Vout = +56 dBmV @ 870 Mhz Equiv) (Vout = +58 dBmV @ 870 Mhz Equiv)	112-Channel FLAT 79-Channel FLAT 112-Channel, 12db Tilt 79-Channel, 12db Tilt	CSO <sub>112</sub> CSO <sub>79</sub> CSO <sub>112</sub> CSO <sub>79</sub>	_ _ _ _	-64 -68 -64 -69	-62 -66 -62 -67	dBc
Cross Modulation Distortion @ Ch 2 (V <sub>out</sub> = +48 dBmV/ch., FM = 55 MHz) (V <sub>out</sub> = +48 dBmV/ch., FM = 55 MHz) (V <sub>out</sub> = +56 dBmV @ 870 Mhz Equiv) (V <sub>out</sub> = +58 dBmV @ 870 Mhz Equiv)	112-Channel FLAT 79-Channel FLAT 112-Channel, 12db Tilt 79-Channel, 12db Tilt	$\begin{array}{c} XMD_{112} \\ XMD_{79} \\ XMD_{112} \\ XMD_{79} \end{array}$	_ _ _ _	-57 -59 -52 -55	-55 -57 -50 -53	dBc
Composite Triple Beat  (Vout = +48 dBmV/ch., Worst Case) 112-Channel FLAT  (Vout = +48 dBmV/ch., Worst Case) 79-Channel FLAT  (Vout = +56 dBmV @ 870 Mhz Equiv) 112-Channel, 12db Tilt  (Vout = +58 dBmV @ 870 Mhz Equiv) 79-Channel, 12db Tilt		CTB <sub>112</sub> CTB <sub>79</sub> CTB <sub>112</sub> CTB <sub>79</sub>	_ _ _ _	-59 -66 -57 -63	-57 -64 -55 -61	dBc
Noise Figure	50 MHz 550 MHz 750 MHz 870 MHz	NF	_ _ _ _	5.5 5.5 5.8 6.0	_ _ _ _	dB
DC Current (V <sub>DC</sub> = 24 V, T <sub>C</sub> = 45°C)	I <sub>DC</sub>	420	440	460	mA	



**ARCHIVE INFORMATION** 

# **PACKAGE DIMENSIONS**





- NOTES:
  1. DIMENSIONS ARE IN INCHES.
  2. INTERPRET DIMENSIONS AND INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.

	INCHES		MILLIN	MILLIMETERS	
DIM	MIN	MAX	MIN	MAX	
Α		1.775		45.085	
В		1.085		27.559	
С		0.840		21.336	
D	0.015	0.021	0.381	0.533	
E	0.465	0.510	11.811	12.954	
F	0.300	0.325	7.62	8.255	
G	0.100 BSC 0.156 BSC		2.540 BSC		
J			3.962 BSC		
K	0.315	0.355	8.001	9.017	
L	1.000 BSC		25.400 BSC		
N	0.165 BSC		4.191 BSC		
P	0.100 BSC		2.540 BSC		
Q	0.148	0.168	3.759	4.267	
R		0.600		15.24	
S	1.500 BSC 0.200 BSC		38.100 BSC		
U			5.080 BSC		
٧		0.250		6.350	
W	0.435		11.049		
Х	0.400 BSC		10.160 BSC		
Υ	0.152	0.163	3.861	4.140	
Z	0.009	0.011	0.229	0.279	

- STYLE 1:
  PIN 1. RF INPUT
  2. GROUND
  3. GROUND
  4. DELETED
  5. VDC
  6. DELETED
  7. GROUND
  8. GROUND
  9. RF OUTPUT

**CASE 1302-01 ISSUE E** 



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